DECLARATION AND POWER OF ATTORNEY FOR PATENT APPLICATION

DOCKET NO. TS03-287-51

As a below named Inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled High Temperature Hydrogen Annealing Of A Gate Insulator Layer To Increase Etching Selectivity Between Conductive Gate Structure And Gate Insulator Layer

the specification of which (check one)			
X is attached hereto.	•		
Application Serial No.			
and was amended on	applicable)		
I hereby state that I have reviewed and	understand the contents of the above.	ove Identified specification including the c	
l acknowledge the duty to disclose info Title 37, Code of Federal Regulations,	rmation which is material to the e $\S1.56(a)$.	xamination of this application in accordance	c with
I hereby claim foreign priority benefits inventor's certificate listed below and I having a filing date before that of the a	under Title 35, United States Cod	le §119 of any foreign application(s) for pa	tent or hificate
Prior Foreign Application(s)		Priority Claimed:	
(Number)	(Country)	(Day/Month/Year Filed)	
(Number)	(Country)	(Day/Month/Year Filed)	
I hereby claim the benefit under Title as the subject matter of each of the clamanner provided by the first paragraph information as defined in Title 37, Corapplication and the national or PCT in	35, United States Code §120 of an ims of this application is not discluded Title 35, United States Code, de of Federal Regulations, §1.566 ternational filing date of this applications.	y United States application(s) listed below osed in the prior United States application in \$112, I acknowledge the duty to disclose many which occurred between the filing date of cation:	and, insofar in the aterial The prior
(Application Serial No.)	(Filing Date) (Status)	(patented, pending, abandoned)	
I hereby declare that all statements ma belief are believed to be true; and furt the like so made are punishable by fin and that such willful false statements to	de herein of my own knowledge a her that these statements were mad e or imprisonment, or both, under may jeopardize the validity of the	re true and that all statements made on info le with the knowledge that willful false stat Section 1001 of Title 18 of the United Stat application or any patent issued thereon.	rmation and ements and les Code
POWER OF ATTORNEY: As a name application and transact all business in	ed inventor, I hereby appoint the f n the Patent and Trademark Office	ollowing attorney(s) and/or agent(s) to proseconnected therewith. (list name & registration	ecute this tion no.)
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